CD54HC4514/3A CD54HCT4514/3A

Switching Speed (Limits with black dots (*) are tested 100%.) SWITCHING CHARACTERISTICS (C_L = 50 pF, Input t, t_l = 6 ns)

CHARACTERISTIC	T			25	°C		-55°C to +125°C				
	SYMBOL	Vcc	HC		HCT		54HC		54HCT		UNITS
		V	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Propagation Delay		2	_	275	_	_	_	115		-	
Select to Outputs		4.5	_	55•	l —	55•	l —	83•	<u> </u>	83•	
		6	_	47	_			71	<u> </u>		
	7 .	2		225		_		340	_	— ¹	
LE to Outputs	t _{PLH}	4.5		45•	l —	50∙	-	68•		75∙	ns
	t _{PHL}	6	_	38	_	l —	_	58	_	-	
		2		175	_			265	_	-	113
E to Outputs		4.5	_	35∙	_	40•	_	53•	-	60•	
2 10 001,511		6	l –	30		l –	_	45	-	-	
Output Transition Time	1 .	2		75	_	T —	_	110	_	—	
	t _{TLH}	4.5	_	15	<u> </u>	15		22	-	22	
	t _{THL}	6	l –	13	-			19	<u> </u>		
Input Capacitance	Cı	1 –	T	10	T	10	T —	10		10	pF

Burn-In Test-Circuit Connections (Use Static II for /3A burn-in and Dynamic for Life Test.)

Static		STATIC BURN-I	NI	STATIC BURN-IN II				
	OPEN	GROUND	V _{cc} (6V)	OPEN	GROUND	V _{cc} (6V)		
CD54HC/HCT4514	4-11,13-20	1-3,12,21-23	24	4-11,13-20	12	1-3,21-24		
					OSCILLATOR			
Dynamic	OPEN	GROUND	1/2 V _{cc} (3V)	V _{cc} (6V)	50 kHz	25 kHz		
CD54HC/HCT4514		2,3,12	4-11,13-20	21,22,24	1	23		

NOTE: Each pin except Vcc and Gnd will have a resistor of 2k-47k ohms.

4-to-16-Line Decoder with Input Latches

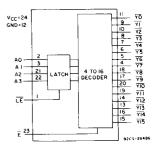
CD54HC4515/3A CD54HCT4515/3A

The RCA CD54HC4515 and CD54HCT4515 are high-speed silicon-gate devices consisting of a 4-bit strobed latch and a 4-to-16-line decoder. The selected output is enabled by a low on the enable input (Ē). A high on Ē inhibits selection of any output. Demultiplexing is accomplished by using the Ē input as the data input and the select inputs (A0-A3) as addresses. This Ē input also serves as a chip select when these devices are cascaded.

When Latch Enable (LE) is high the output follows changes in the inputs. When LE is low the output is isolated from changes in the input and remains at the level (low) it had before the latches were enabled. These devices, enhanced versions of the equivalent CMOS types, can drive 10 LSTTL loads.

Package Specifications

See Section 11, Fig. 15



FUNCTIONAL DIAGRAM

CD54HC4515/3A CD54HCT4515/3A

Static Electrical Characteristics (Limits with black dots (•) are tested 100%)

		TEST CONDITIONS								
				// IOT		V	in	1		
			HC	/HCT		НС	HCT	LIN	IITS	
CHARACTERI	STICS	V _{DD}	v o	Io	V _{cc} or GND	V _{IL} or V _{IH}	V _{IL} or V _{IH}	MIN.	MAX.	UNITS
Quiescent	25° C	6	_	<u> </u>	6, 0	_	_	_	8•	
Device Current	-55° C	6	_		6, 0		_	_	160•	μA
Icc	+125°C				0, 0				100-	

The complete static electrical test specification consists of the above by-type static tests combined with the standard static tests in the beginning of this section.

HCT INPUT LOADING TABLE

INPUT	UNIT LOAD*
A0 - A3	0.15
ĹĒ	0.85
Ē	0.3

*Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 360 μ A max. @ 25° C.

Switching Speed (Limits with black dots (*) are tested 100%.) SWITCHING CHARACTERISTICS (C_L = 50 pF, Input t, t, = 6 ns)

CHARACTERISTIC		1	25° C				-55°C to +125°C				
	SYMBOL	Vcc	нс		нст		54HC		54HCT		UNITS
		V	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Propagation Delay		2	_	275	_		_	115	_		
Select to Outputs		4.5	_	55∙	_	55∙	_	83•	_	83•	
•		6	-	47		_	_	71		_	
LE to Outputs	7.	2	_	225	_	_	_	340			
	t _{PLH} t _{PHL}	4.5	l —	45∙	_	50∙	-	68•		75•	ns
		6	_	38	-	l —	_	58		_	
	7	2	-	175		_	_	265	_		
E to Outputs		4.5		35∙	_	40•	_	53∙	_	60∙	
		6	l –	30	_	—	_	45		_]	
Output Transition Time		2	I —	75	_	_	_	110	_		
	t _{TLH}	4.5	l —	15	_	15	_	22	l —	22	
	t _{THL}	6	_	13		-		19	l —	-	
Input Capacitance	Cı	Ī		10	_	10	_	10		10	pF

Burn-In Test-Circuit Connections (Use Static II for /3A burn-in and Dynamic for Life Test.)

Ctatia		STATIC BURN-	N I		STATIC BURN-IN II			
Static	OPEN	GROUND	GROUND V _{cc} (6V) OPEN GROUND		V _{cc} (6V)			
CD54HC/HCT4515	4-11,13-20	1-3,12,21-23	24	4-11,13-20	12	1-3,21-24		
Dymania					OSCILLATOR			
Dynamic	OPEN	GROUND	1/2 V _{cc} (3V)	V _{cc} (6V)	50 kHz	25 kHz		
CD54HC/HCT4515		2,3,12	4-11,13-20	21,22,24	1	23		

NOTE: Each pin except Vcc and Gnd will have a resistor of 2k-47k ohms.